

# LP8340 Low Dropout, Low IQ, 1.0A CMOS Linear Regulator

Check for Samples: LP8340

### **FEATURES**

- ±1.5% Typical V<sub>OUT</sub> Tolerance
- 420mV Typical Dropout @ 1.0A (V<sub>O</sub> = 5V)
- Wide Operating Range 2.7V to 10V
- Internal 1.0A PMOS Output Transistor
- 19µA Typical Quiescent Current
- Thermal Overload Limiting
- Foldback Current Limiting
- Zener Trimmed Bandgap Reference
- Space Saving WSON package
- Temperature Range
  - LP8340C 0°C to 125°C
  - LP8340I -40°C to 125°C

#### **APPLICATIONS**

- Hard Disk Drives
- Notebook Computers
- Battery Powered Electronics
- Portable Instrumentation

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## **DESCRIPTION**

The LP8340 low-dropout CMOS linear regulator is available in 5V, 3.3V, 2.5V, 1.8V and adjustable output versions. Packaged in the 6ld WSON package and 3ld PFM. The LP8340 can deliver up to 1.0A output current.

Typical dropout voltage is 420mV at 1.0A for the 5.0V version, 540mV at 1.0A for the 3.3V version, 670mV at 1.0A for the 2.5V version and 680mV at 800mA for the 1.8V version.

The LP8340 includes a zener trimmed bandgap voltage reference, foldback current limiting and thermal overload limiting.

The LP8340 features a PMOS output transistor which unlike PNP type low dropout regulators requires no base drive current. This allows the device ground current to remain less than 50µA over operating temperature, supply voltage and irrespective of the load current.

### **Typical Applications**

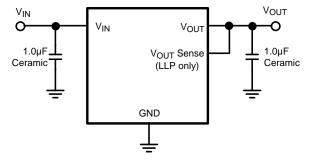


Figure 1. Fixed Vout

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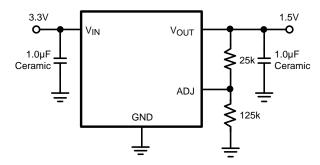


Figure 2. Adjustable V<sub>OUT</sub>

## **Connection Diagrams**

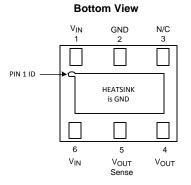


Figure 3. 6-Pin WSON Package Fixed Output Voltage See Package Number NGD0006A

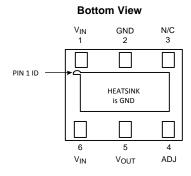


Figure 4. 6-Pin WSON Package Adjustable Output Voltage See Package Number NGD0006A

#### **NOTE**

 $V_{\text{IN}}$  Pins (Pin 1 & 6) must be connected together externally for full 1 amp operation (500mA max per pin).

V<sub>OUT</sub> Sense (Pin 5) must be connected to V<sub>OUT</sub> (Pin 4).

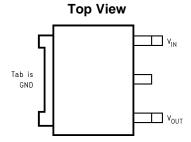


Figure 5. PFM Package See Package Number NDP0003B



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.



## Absolute Maximum Ratings (1)(2)(3)

·	9		
V <sub>IN</sub> , V <sub>OUT</sub> , V <sub>OUT</sub> Sense, ADJ	−0.3V to 12V		
Storage Temperature Range	-65°C to 160°C		
Junction Temperature (T <sub>J</sub> )	150°0		
Power Dissipation		See <sup>(4)</sup>	
ESD Rating	Human Body Model <sup>(5)</sup>	2kV	
	Machine Model	200V	

<sup>(1)</sup> Absolute Maximum ratings indicate limits beyond which damage may occur. Electrical specifications do not apply when operating the device outside of its rated operating conditions.

(2) All voltages are with respect to the potential at the ground pin.

(3) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.

 $P_D = \frac{T_{J(MAX)} - T_A}{Q_{JJ}}$ 

(5) Human body model 1.5kΩ in series with 100pF.

## Operating Ratings<sup>(1)(2)</sup>

Supply Voltage	2.7 to 10V
Temperature Range	
LP8340C	0°C to 125°C
LP8340I	-40°C to 125°C

<sup>(1)</sup> Absolute Maximum ratings indicate limits beyond which damage may occur. Electrical specifications do not apply when operating the device outside of its rated operating conditions.

(2) All voltages are with respect to the potential at the ground pin.

## **LP8340C Electrical Characteristics**

Unless otherwise specified all limits ensured for  $V_{IN} = V_O + 1V$ ,  $C_{IN} = C_{OUT} = 10 \mu F$ ,  $T_J = 25 ^{\circ}C$ . **Boldface** limits apply over the full operating temperature range of  $T_J = 0 ^{\circ}C$  to  $125 ^{\circ}C$ 

Symbol	Parameter	Conditions	Min <sup>(1)</sup>	Typ <sup>(2)</sup>	Max <sup>(1)</sup>	Units
V <sub>IN</sub>	Input Voltage	LP8340-ADJ,1.8, 2.5 LP8340-3.3, 5.0	2.7		10 10	V
V <sub>OUT</sub>	Output Voltage	$ \begin{array}{l} LP8340\text{-ADJ, ADJ} = OUT \\ I_{OUT} = 10\text{mA, V}_{\text{IN}} = 2.7\text{V, T}_{\text{J}} = 25^{\circ}\text{C} \\ 100\mu\text{A} \leq I_{OUT} \leq 800\text{mA, } 3.0\text{V} \leq \text{V}_{\text{IN}} \leq \text{V}_{OUT} + 4\text{V} \\ 800\text{mA} < I_{OUT} \leq 1.0\text{A, } 3.2\text{V} \leq \text{V}_{\text{IN}} \leq \text{V}_{OUT} + 4\text{V} \\ \end{array} $	1.231 1.213 1.213	1.250	1.269 <b>1.288</b> <b>1.288</b>	>
		LP8340-1.8 $I_{OUT}$ = 10mA, $V_{IN}$ = 2.8V, $T_{J}$ = 25°C 100μA ≤ $I_{OUT}$ ≤800mA, 3.2V ≤ $V_{IN}$ ≤6V 800mA < $I_{OUT}$ ≤1.0A, 3.4V ≤ $V_{IN}$ ≤6V	1.773 1.746 1.746	1.800	1.827 <b>1.854</b> <b>1.854</b>	<b>&gt;</b>
		LP8340-2.5 $I_{OUT} = 10$ mA, $V_{IN} = 3.8$ V, $T_{J} = 25$ °C $100$ μA $\leq I_{OUT} \leq 1.0$ A, $3.8$ V $\leq V_{IN} \leq 6.5$ V	2.463 <b>2.425</b>	2.500	2.538 <b>2.575</b>	V
		LP8340-3.3 $I_{OUT} = 10$ mA, $V_{IN} = 4.3$ V $T_{J} = 25$ °C $100$ μA $\leq I_{OUT} \leq 1.0$ A, $4.3$ V $\leq V_{IN} \leq 7.5$ V	3.250 <b>3.201</b>	3.300	3.350 <b>3.399</b>	V
		LP8340-5.0 $I_{OUT} = 10 \text{mA}, \ V_{IN} = 6 \text{V}, \ T_J = 25 ^{\circ}\text{C}$ 100 $\mu$ A ≤ $I_{OUT}$ ≤1.0A, 6V ≤ $I_{IN}$ ≤9V	4.925 <b>4.850</b>	5.000	5.075 <b>5.150</b>	V

Product Folder Links: LP8340

<sup>(4)</sup> Maximum Power dissipation for the device is calculated using the following equations: θJA where T<sub>J(MAX)</sub> is the maximum junction temperature, T<sub>A</sub> is the ambient temperature, and θ<sub>JA</sub> is the junction-to-ambient thermal resistance. The value of the θ<sub>JA</sub> for the WSON package is specifically dependant on the PCB trace area, trace material, and the number of layers and thermal vias. For improved thermal resistance and power dissipation for the WSON package, refer to Application Note AN-1187 (SNOA401).

<sup>(1)</sup> All limits are specified by testing or statistical analysis.

<sup>(2)</sup> Typical Values represent the most likely parametric norm.



## LP8340C Electrical Characteristics (continued)

Unless otherwise specified all limits ensured for  $V_{IN} = V_O + 1V$ ,  $C_{IN} = C_{OUT} = 10 \mu F$ ,  $T_J = 25 ^{\circ}C$ . **Boldface** limits apply over the full operating temperature range of  $T_J = 0 ^{\circ}C$  to  $125 ^{\circ}C$ 

Symbol	Parameter	Conditions	Min <sup>(1)</sup>	Typ <sup>(2)</sup>	Max <sup>(1)</sup>	Units
$\Delta V_{O}$	Load Regulation	LP8340-ADJ, ADJ=OUT I <sub>OUT</sub> = 1mA to 1.0A, V <sub>IN</sub> = 3.2V		6	25	
		LP8340-1.8 $I_{OUT}$ = 1mA to 1.0A, $V_{IN}$ = 3.4V		8	30	
		LP8340-2.5 $I_{OUT}$ = 1mA to 1.0A, $V_{IN}$ = 3.5V		15	50	mV
		LP8340-3.3 I <sub>OUT</sub> = 1mA to 1.0A, V <sub>IN</sub> = 4.3V		20	75	
		LP8340-5.0 $I_{OUT} = 1$ mA to 1.0A, $V_{IN} = 6$ V		25	100	
$\Delta V_{O}$	Line Regulation	$V_{OUT} + 0.5V \le V_{IN} \le 10V, I_{OUT} = 25mA^{(3)}$		4	15	mV
$V_{IN} - V_{O}$	Dropout Voltage (3)(4)	LP8340-1.8 I <sub>OUT</sub> = 800mA		680	1400	
		LP8340-2.5 I <sub>OUT</sub> = 800mA		550	1000	
		LP8340-2.5 I <sub>OUT</sub> = 1.0A		670	1300	
		LP8340-3.3 LP8340-ADJ, V <sub>OUT</sub> = 3.3V, I <sub>OUT</sub> = 800mA		420	800	mV
		LP8340-3.3 LP8340-ADJ, I <sub>OUT</sub> = 1.0A		540	1000	
		LP8340-5.0 I <sub>OUT</sub> = 800mA		330	650	
		LP8340-5.0 I <sub>OUT</sub> = 1.0A		420	800	
$I_Q$	Quiescent Current	V <sub>IN</sub> ≤10V		19	50	μA
	Minimum Load Current	V <sub>IN</sub> - V <sub>OUT</sub> ≤4V			100	μA
I <sub>LIMIT</sub>	Foldback Current Limit	V <sub>IN</sub> - V <sub>OUT</sub> >5V		450		mA
		V <sub>IN</sub> - V <sub>OUT</sub> <4V		1600		IIIA
	Ripple Rejection Ratio	$V_{IN}$ (dc) = $V_{OUT} + 2V$ $V_{IN}$ (ac) = 1 $V_{P-P}$ @ 120Hz	48	55		dB
$T_{SD}$	Thermal Shutdown Temp. Thermal Shutdown Hyst.		160 10		°C	
	ADJ Input Leakage Current	V <sub>ADJ</sub> = 1.5V or 0V		±0.01	±100	nA
	V <sub>OUT</sub> Leakage Current	LP8340-ADJ ADJ = OUT, V <sub>OUT</sub> = 2V, V <sub>IN</sub> = 10V			10	
		LP8340-1.8, V <sub>OUT</sub> = 2.5V, V <sub>IN</sub> = 10V			10	
		LP8340-2.5, V <sub>OUT</sub> = 3.5V, V <sub>IN</sub> = 10V			10	μA
		LP8340-3.3, V <sub>OUT</sub> = 4V, V <sub>IN</sub> = 10V			10	
		LP8340-5.0, V <sub>OUT</sub> = 6V, V <sub>IN</sub> = 10V			10	
e <sub>n</sub>	Output Noise	10Hz to 10kHz, $R_L = 1k\Omega$ , $C_{OUT} = 10\mu F$		250		μVrms

Condition does not apply to input voltages below 2.7V since this is the minimum input operating voltage. Dropout voltage is measured by reducing  $V_{\text{IN}}$  until  $V_{\text{O}}$  drops 100mV from its normal value.

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## **LP8340I Electrical Characteristics**

Unless otherwise specified all limits ensured for  $V_{IN} = V_O + 1V$ ,  $C_{IN} = C_{OUT} = 10 \mu F$ ,  $T_J = 25 ^{\circ}C$ . **Boldface** limits apply over the full operating temperature range of  $T_J = -40 ^{\circ}C$  to  $125 ^{\circ}C$ 

Symbol Parameter		Conditions	Min <sup>(1)</sup>	Typ <sup>(2)</sup>	Max <sup>(1)</sup>	Units
V <sub>IN</sub>	Input Voltage	LP8340-ADJ,1.8, 2.5 LP8340-3.3, 5.0	2.7		10 10	V
V <sub>ОUТ</sub>	Output Voltage	$\begin{split} \text{LP8340-ADJ, ADJ} &= \text{OUT} \\ \text{I}_{\text{OUT}} &= 10\text{mA, V}_{\text{IN}} = 2.7\text{V, T}_{\text{J}} = 25^{\circ}\text{C} \\ 100\mu\text{A} &\leq \text{I}_{\text{OUT}} \leq 800\text{mA, } 3.0\text{V} \leq \text{V}_{\text{IN}} \leq \text{V}_{\text{OUT}} + 4\text{V} \\ 800\text{mA} &< \text{I}_{\text{OUT}} \leq 1.0\text{A, } 3.2\text{V} \leq \text{V}_{\text{IN}} \leq \text{V}_{\text{OUT}} + 4\text{V} \end{split}$	1.231 1.213 1.213	1.250	1.269 <b>1.288</b> <b>1.288</b>	V
		$\begin{split} \text{LP8340-1.8} \\ \text{I}_{\text{OUT}} &= 10 \text{mA},  \text{V}_{\text{IN}} = 2.8 \text{V},  \text{T}_{\text{J}} = 25 ^{\circ} \text{C} \\ 100 \mu \text{A} \leq & \text{I}_{\text{OUT}} \leq 800 \text{mA},  3.2 \text{V} \leq & \text{V}_{\text{IN}} \leq 6 \text{V} \\ 800 \text{mA} < & \text{I}_{\text{OUT}} \leq 1.0 \text{A},  3.4 \text{V} \leq & \text{V}_{\text{IN}} \leq 6 \text{V} \end{split}$	1.773 1.746 1.746	1.800	1.827 <b>1.854</b> <b>1.854</b>	V
		LP8340-2.5 $I_{OUT} = 10$ mA, $V_{IN} = 3.8$ V, $T_{J} = 25$ °C $100$ µA $\leq I_{OUT} \leq 1.0$ A, $3.8$ V $\leq V_{IN} \leq 6.5$ V	2.463 <b>2.425</b>	2.500	2.538 <b>2.575</b>	V
		LP8340-3.3 $I_{OUT} = 10 \text{mA}, V_{IN} = 4.3 \text{V T}_{J} = 25 ^{\circ}\text{C}$ $100 \mu \text{A} \leq I_{OUT} \leq 1.0 \text{A}, 4.3 \text{V} \leq V_{IN} \leq 7.5 \text{V}$	3.250 <b>3.201</b>	3.300	3.350 <b>3.399</b>	V
		LP8340-5.0 $I_{OUT} = 10$ mA, $V_{IN} = 6$ V, $T_{J} = 25$ °C $100$ µA $\leq I_{OUT} \leq 1.0$ A, $6$ V $\leq V_{IN} \leq 9$ V	4.925 <b>4.850</b>	5.000	5.075 <b>5.150</b>	V
ΔV <sub>O</sub>	Load Regulation	LP8340-ADJ, ADJ=OUT I <sub>OUT</sub> = 1mA to 1.0A, V <sub>IN</sub> = 3.2V		6	25	
		LP8340-1.8 I <sub>OUT</sub> = 1mA to 1.0A, V <sub>IN</sub> = 3.4V		8	30	
		LP8340-2.5 $I_{OUT}$ = 1mA to 1.0A, $V_{IN}$ = 3.5V		15	50	mV
		LP8340-3.3 I <sub>OUT</sub> = 1mA to 1.0A, V <sub>IN</sub> = 4.3V		20	75	
		LP8340-5.0 $I_{OUT} = 1$ mA to 1.0A, $V_{IN} = 6V$		25	100	
ΔV <sub>O</sub>	Line Regulation	$V_{OUT} + 0.5V \le V_{IN} \le 10V$ , $I_{OUT} = 25mA^{(3)}$		4	15	mV
V <sub>IN</sub> - V <sub>O</sub>	Dropout Voltage <sup>(3)(4)</sup>	LP8340-1.8 I <sub>OUT</sub> = 800mA		680	1400	
		LP8340-2.5 I <sub>OUT</sub> = 800mA		550	1000	
		LP8340-2.5 I <sub>OUT</sub> = 1.0A		670	1300	
		LP8340-3.3 LP8340-ADJ, $V_{OUT} = 3.3V$ , $I_{OUT} = 800$ mA		420	800	mV
		LP8340-3.3 LP8340-ADJ, I <sub>OUT</sub> = 1.0A		540	1000	
		LP8340-5.0 I <sub>OUT</sub> = 800mA		330	650	
		LP8340-5.0 I <sub>OUT</sub> = 1.0A		420	800	
Q	Quiescent Current	V <sub>IN</sub> ≤10V		19	50	μΑ
	Minimum Load Current	V <sub>IN</sub> - V <sub>OUT</sub> ≤4V			100	μA
LIMIT	Foldback Current Limit	V <sub>IN</sub> - V <sub>OUT</sub> >5V		450		۸ ـــ ۸
		V <sub>IN</sub> - V <sub>OUT</sub> <4V		1600		mA
	Ripple Rejection Ratio	$V_{IN} (dc) = V_{OUT} + 2V$ $V_{IN} (ac) = 1 V_{P-P} @ 120Hz$	48	55		dB

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All limits are specified by testing or statistical analysis. Typical Values represent the most likely parametric norm.

Condition does not apply to input voltages below 2.7V since this is the minimum input operating voltage.

Dropout voltage is measured by reducing V<sub>IN</sub> until V<sub>O</sub> drops 100mV from its normal value.



## **LP8340I Electrical Characteristics (continued)**

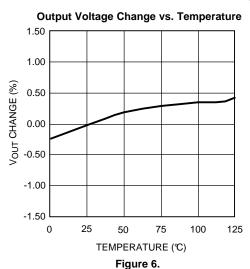
Unless otherwise specified all limits ensured for  $V_{IN} = V_O + 1V$ ,  $C_{IN} = C_{OUT} = 10 \mu F$ ,  $T_J = 25 ^{\circ}C$ . **Boldface** limits apply over the full operating temperature range of  $T_J = -40 ^{\circ}C$  to  $125 ^{\circ}C$ 

Symbol	Parameter	Conditions	Min <sup>(1)</sup>	Typ <sup>(2)</sup>	Max <sup>(1)</sup>	Units
T <sub>SD</sub>	Thermal Shutdown Temp. Thermal Shutdown Hyst.			160 10		°C
	ADJ Input Leakage Current	V <sub>ADJ</sub> = 1.5V or 0V		±0.01	±100	nA
	V <sub>OUT</sub> Leakage Current	LP8340-ADJ ADJ = OUT, V <sub>OUT</sub> = 2V, V <sub>IN</sub> = 10V			10	
		LP8340-1.8, $V_{OUT} = 2.5V$ , $V_{IN} = 10V$			10	
		LP8340-2.5, V <sub>OUT</sub> = 3.5V, V <sub>IN</sub> = 10V			10	μΑ
		LP8340-3.3, V <sub>OUT</sub> = 4V, V <sub>IN</sub> = 10V			10	
		LP8340-5.0, V <sub>OUT</sub> = 6V, V <sub>IN</sub> = 10V			10	
e <sub>n</sub>	Output Noise	10Hz to 10kHz, $R_L = 1k\Omega$ , $C_{OUT} = 10\mu F$		250		μVrms

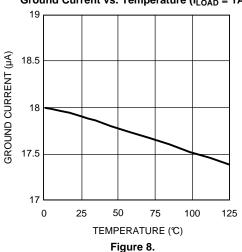


## **Typical Performance Characteristics**

Unless otherwise specified,  $V_{IN} = V_O + 1.5V$ ,  $C_{IN} = C_{OUT} = 10 \mu F$  X7R ceramic,  $T_J = 25 ^{\circ} C$ 







### **Ground Current vs. Input Voltage**

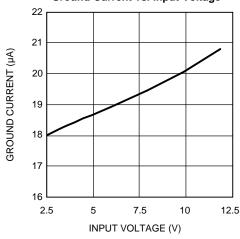


Figure 10.

Dropout Voltage vs. Load Current

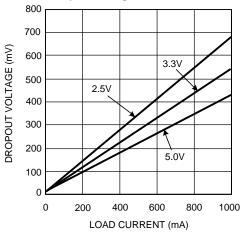
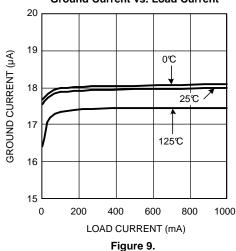


Figure 7.

#### **Ground Current vs. Load Current**



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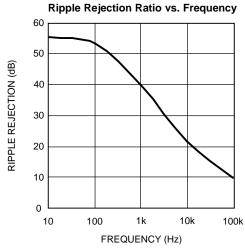


Figure 11.



## **Typical Performance Characteristics (continued)**

Unless otherwise specified,  $V_{IN} = V_O + 1.5V$ ,  $C_{IN} = C_{OUT} = 10 \mu F$  X7R ceramic,  $T_J = 25 ^{\circ} C$ 

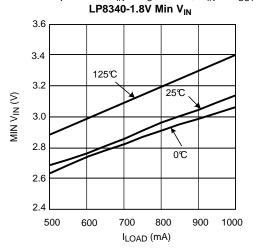


Figure 12.

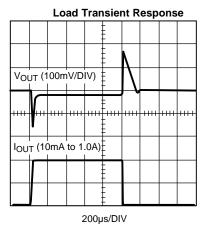


Figure 14.

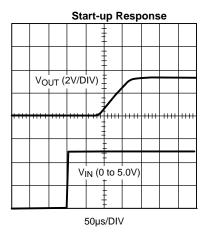


Figure 16.

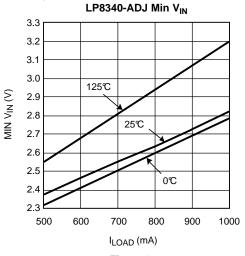


Figure 13.

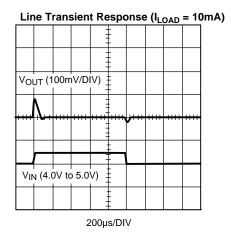
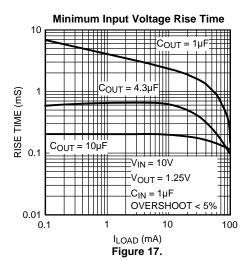


Figure 15.

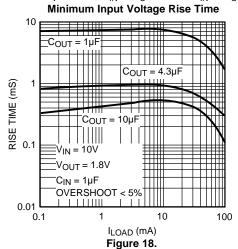


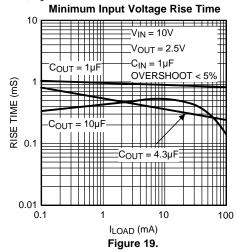
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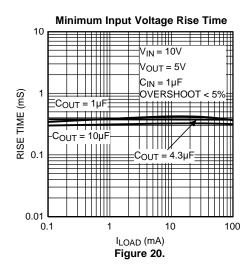


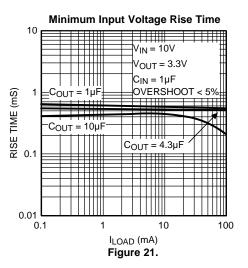
## **Typical Performance Characteristics (continued)**

Unless otherwise specified,  $V_{IN} = V_O + 1.5V$ ,  $C_{IN} = C_{OUT} = 10 \mu F$  X7R ceramic,  $T_J = 25 ^{\circ}C$ 











#### **APPLICATIONS SECTION**

#### **GENERAL INFORMATION**

The LP8340 is a low-dropout, low quiescent current linear regulator. As shown in Figure 22 it consists of a 1.25V reference, error amplifier, MOSFET driver, PMOS pass transistor and for the fixed output versions, an internal feedback network ( $R_1/R_2$ ). In addition, the device is protected from overload by a thermal shutdown circuit and a foldback current limit circuit

The 1.25V reference is connected to the inverting input of the error amplifier. Regulation of the output voltage is achieved by means of negative feedback to the non-inverting input of the error amplifier. Feedback resistors  $R_1$  and  $R_2$  are either internal or external to the device, depending on whether it is a fixed voltage version or the adjustable version. The negative feedback and high open loop gain of the error amplifier cause the two inputs of the error amp to be virtually equal in voltage. If the output voltage changes due to load changes, the error amplifier and MOSFET driver provide the appropriate drive to the pass transistor to maintain the error amplifier's inputs as virtually equal.

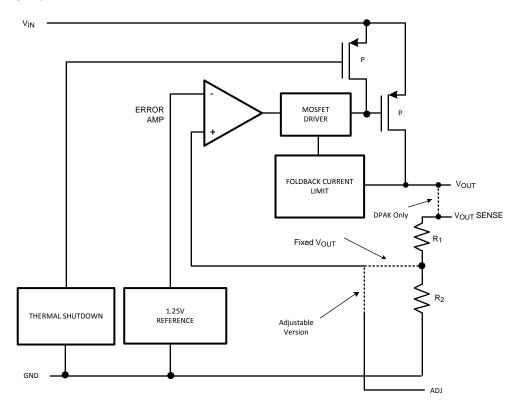


Figure 22. LP8340 Functional Block Diagram

#### **EXTERNAL CAPACITOR**

An Input capacitor of  $1\mu F$  or greater is required between the LP8340  $V_{IN}$  pin and ground. While  $1\mu F$  will provide adequate bypassing of the  $V_{IN}$  supply larger values of input capacitor (i.e.  $10\mu F$ ) can provide improved bypassing of power supply noise.

Stable operation can be achieved with an output capacitor of  $1\mu F$  or greater, either ceramic X7R dielectric or aluminum/tantalum electrolytic. While the minimum capacitor value is  $1\mu F$ , the typical output capacitor values selected range from  $1\mu F$  to  $10\mu F$ . The larger values provide improved load-transient response, power supply rejection and stability.



## **OUTPUT VOLTAGE SETTING (ADJ VERSION ONLY)**

The output voltage is set according to the amount of negative feedback (Note that the pass transistor inverts the feedback signal). This feedback is determined by  $R_1$  and  $R_2$  with the resulting output voltage represented by the following equation:

$$V_{O} = V_{REF} \left[ \frac{R_1}{R_2} + 1 \right] \tag{1}$$

Use the following equation to determine the values of  $R_1$  and  $R_2$  for a desired  $V_{OUT}$  ( $R_2$  = 100k $\Omega$  is recommended).

$$R_1 = R_2 \left[ \frac{V_0}{1.25V} - 1 \right]$$
 (2)

#### MINIMUM LOAD CURRENT

A minimum load of  $100\mu A$  is required for regulation and stability over the entire operating temperature range. If actual load current fall below  $100\mu A$  it is recommended that a resistor of value  $R_L = V_O/100\mu A$  be placed between  $V_O$  and ground.

### START UP CONSIDERATIONS

Under certain operating conditions, overshoot of  $V_{OUT}$  at start-up can occur. The observed overshoot is a function of rise time of  $V_{IN}$  waveform,  $C_{OUT}$ , start-up load current, and  $V_{IN}$ - $V_{OUT}$  differential. The relationship between these conditions is shown in the Typical Performance Characteristics curves (Minimum Input Voltage Rise Time).  $V_{IN}$  rise times above the curve result in <5% overshoot.

Customers are encouraged to check the suitability of LP8340 in their specific application.

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## **REVISION HISTORY**

Cr	nanges from Revision C (April 2013) to Revision D	Pa	ge
•	Changed layout of National Data Sheet to TI format		11



## PACKAGE OPTION ADDENDUM

10-Dec-2020

#### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
LP8340ILDX-ADJ/NOPB	ACTIVE	WSON	NGD	6	4500	RoHS & Green	SN	Level-3-260C-168 HR	0 to 125	L078B	Samples

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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# **PACKAGE MATERIALS INFORMATION**

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## TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	_	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LP8340ILDX-ADJ/NOPB	WSON	NGD	6	4500	330.0	12.4	3.6	3.2	1.0	8.0	12.0	Q1

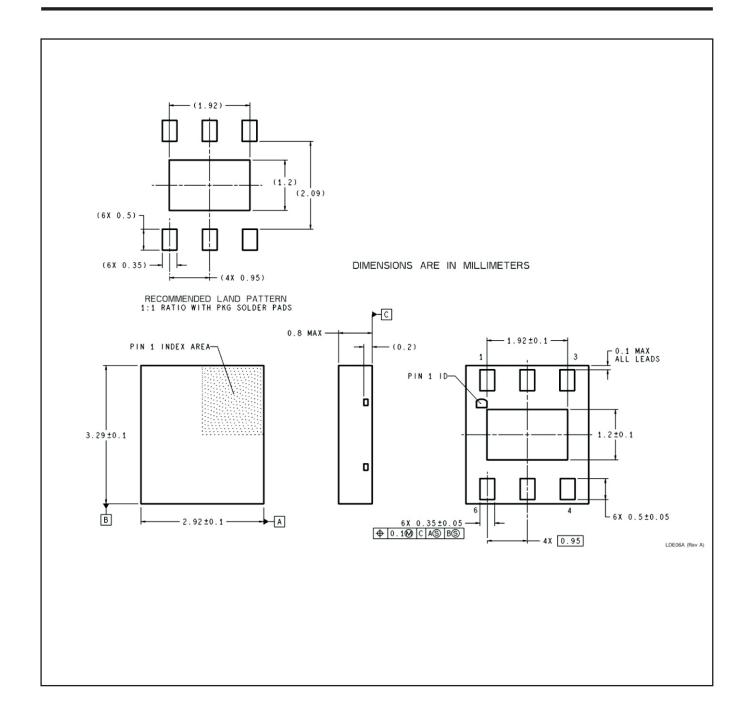
# **PACKAGE MATERIALS INFORMATION**

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### \*All dimensions are nominal

Device	Package Type Package Drawing		Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LP8340ILDX-ADJ/NOPB	WSON	NGD	6	4500	356.0	356.0	36.0



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